

# National Institute of Technology, Delhi

Name of the Examination: B. Tech

Branch : ECE

Semester : IV

Title of the Course : Analog Electronics

Course Code : ECB 252

Time: 2 Hours

Maximum Marks: 25

- Questions are printed on BOTH sides. Answers should be CLEAR AND TO THE POINT.
- All parts of a single question must be answered together. ELSE QUESTION SHALL NOT BE EVALUATED.

1. In the Darlington stage shown in figure 1,  $V_C = 24\text{ V}$ ,  $\beta_1 = 24$ ,  $\beta_2 = 39$ ,  $V_{BE} = 0.6\text{ V}$ ,  $R_C = 330\ \Omega$  and  $R_E = 120\ \Omega$ . If at the Q-pt,  $V_{CE2} = 6\text{ V}$ , determine (a) value of resistance  $R$ , (b) stability factor  $S = d_{IC}/d_{IC01}$ . [4]
2. Given in the two-battery transistor circuit in figure 2, find the expression for stability factor,  $S$ . You may neglect  $V_{BE}$ . [2]
3. Calculate  $I_C$ ,  $I_B$  and  $h_{FE}$  for the switching circuit as shown in figure 3, when  $Q_1$  is switched into saturation. [2]
4. Given the load line plot with defined Q-pt in figure 4, determine the values of  $V_{CC}$ ,  $R_C$  and  $R_B$  for a fixed bias configuration of transistor. [3]
5. For the emitter bias network shown in figure 5, determine (a)  $I_B$ , (b)  $I_C$ , (c)  $V_{CE}$ , (d)  $V_C$  and (e)  $V_E$ . [5]
6. Determine the quiescent currents ( $I_E$ ,  $I_B$  and  $I_C$ ) and the Collector- Emitter voltage for Ge transistor with  $\beta = 50$  in the self-biasing arrangement as shown in figure 6, where,  $V_{CC} = 20\text{ V}$ ,  $R_C = 2\text{ K}$ ,  $R_E = 0.1\text{ K}$ ,  $R_1 = 100\text{ K}$ ,  $R_2 = 5\text{ K}$  and  $V_{BE} = 0.2\text{ V}$ . Also find the stability factor  $S$ . [5]
7. Write True (T)/ False (F) only, against each of the following statements: [1x4 = 4]
  - (a) In h-parameter equivalent model of transistor, h-parameters are both real and imaginary number.
  - (b) Compensation bias techniques refer to use of temperature sensitive devices.
  - (c) For input signal, having magnitude greater than  $V_{BE}$ , transistor will always be driven in cut off region.
  - (d) Transistor means transfer of resistance.

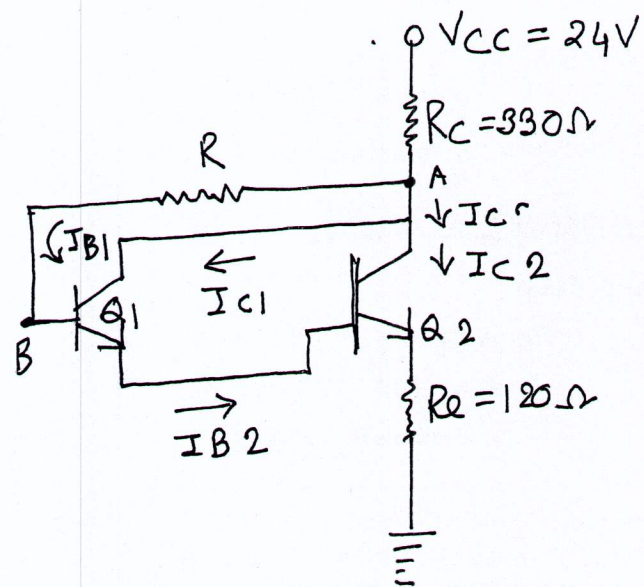


Figure 1

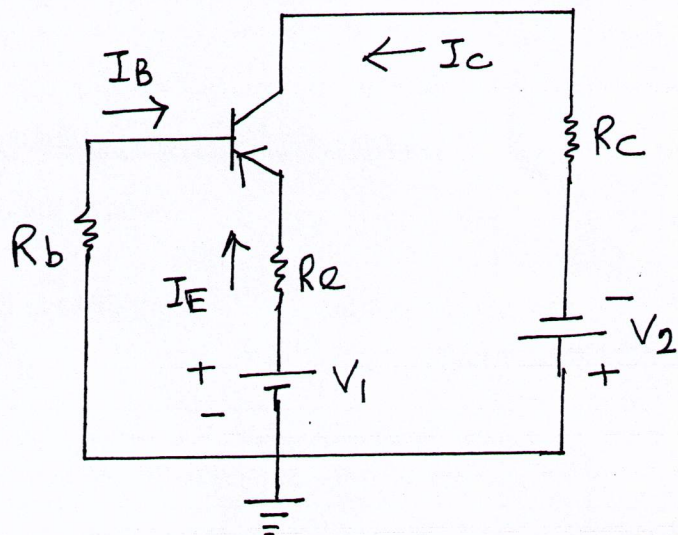


Figure 2

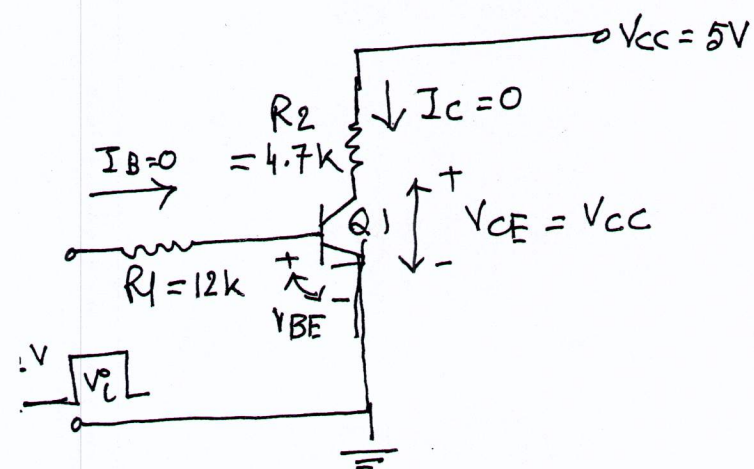


Figure 3

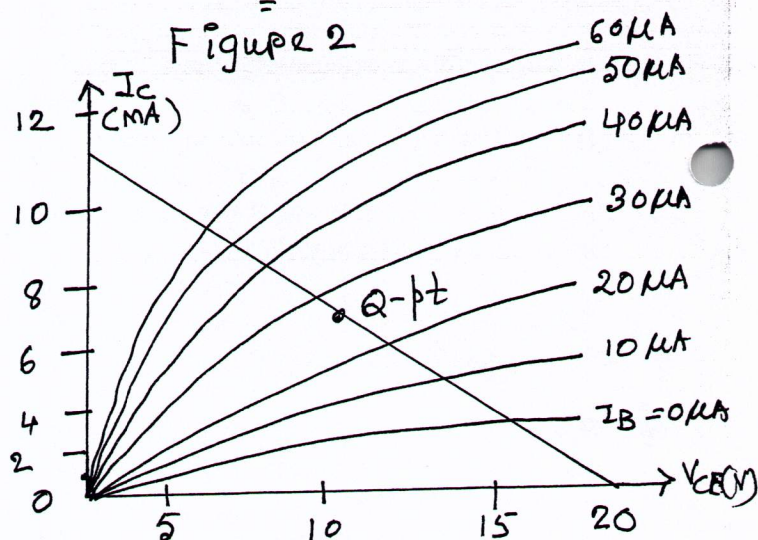


Figure 4

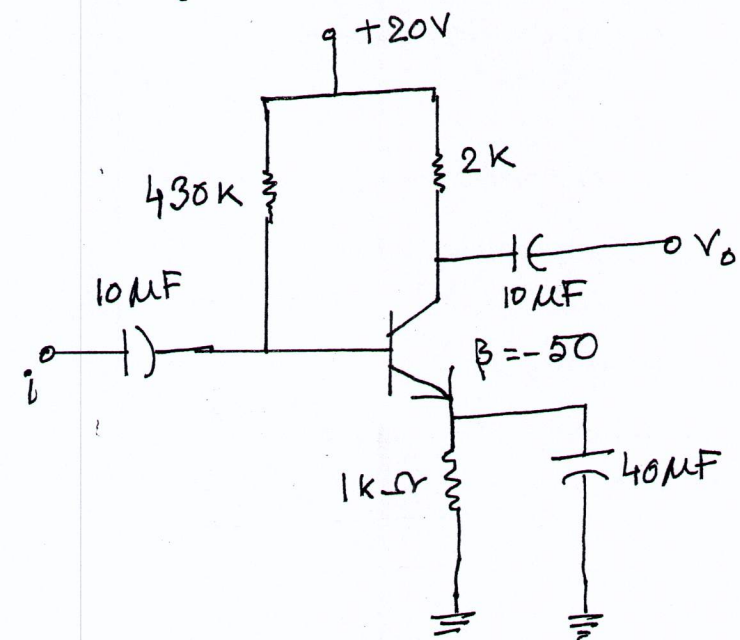


Figure 5

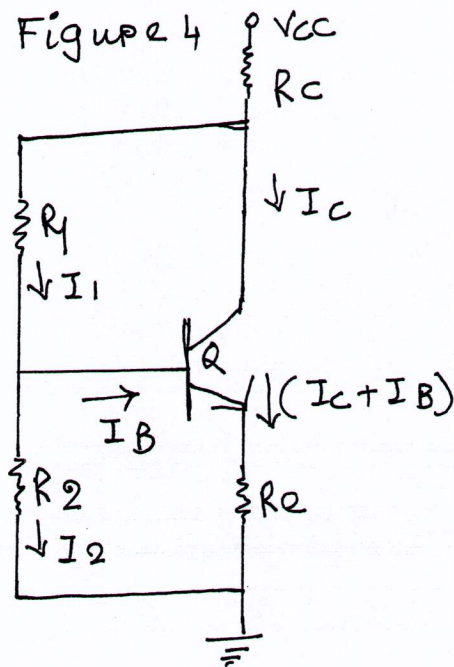


Figure 6